Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Glass

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Current Rating Per Characteristic:

32.00 amperes source cutoff current universal and 5.00 microamperes forward current, average peak

Power Rating Per Characteristic:

1.0 watts small-signal input power, common-emitter outside diameter

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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